

Supporting Information

Patterning of Metal Oxide Thin Films using H₂/He Atmospheric Pressure Plasma Jet

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Sample preparation:

The copper oxide (Cu₂O) films were deposited electrochemically on ITO coated glass substrate. Electrodeposition solution comprised of 0.4 M CuSO₄·H₂O and 3 M Lactic Acid (>85%, Sigma-Aldrich, UK), the pH of the plating solution was brought to pH 12 by addition of 5 M NaOH solution. The Cu₂O layer was grown potentiostatically (PGSTAT100, Autolab, Windsor Scientific, UK) at -0.5 V vs. Ag/AgCl reference electrode using a large area copper wire counter electrode. The total deposition time was 30 minutes at 55°C.

All other films were deposited on SiO₂ (~50 nm) barrier coated float glass (NSG, UK) by atmospheric pressure aerosol assisted chemical vapour deposition on a horizontal bed reactor. The precursor solution was atomised using a piezoelectric ultrasonic humidifier (Johnson Matthey, UK) and passed over the substrate using a carrier gas at a flow rate of 1 L min⁻¹. A stainless steel top plate was positioned 8 mm above the glass substrate to promote laminar flow of gases. The glass substrates were positioned on a heated graphite block with the deposition temperature monitored using platinum-rhodium thermocouples connected to a temperature controller (Eurotherm, UK).

All precursors and solvents were procured from Aldrich and used as received. The glass substrates were cleaned with detergent/water followed by propan-2-ol, then dried in an oven 80 °C. For TiO₂, the precursors solution contained Titanium ethoxide (0.2 g) in toluene (20 mL) was aerosolized and transferred to the CVD chamber at a flow rate of 1 Lmin⁻¹ using N₂ (99.99%, BOC) carrier gas. For SnO₂, coating the precursor solution contained butyltin trichloride (0.2 g) in methanol was aerosolized and transferred to the CVD chamber at a flow rate of 1 L min⁻¹ using compressed air (BOC) carrier gas. For ZnO, the precursors were zinc acetate hydrate (0.2 g) in methanol was aerosolized and transferred to the CVD chamber at a flow rate of 1 L min⁻¹ using N₂ (99.99%, BOC) carrier gas. For WO₃, tungsten hexacarbonyl (0.05 g) in a mixture of acetone (20 mL) and methanol (5 mL) was aerosolized and transferred to the chamber at a flow rate of 1 Lmin⁻¹ using N₂ (99.99%, BOC) carrier gas. For all the coatings the deposition temperature was 500 °C, except for tungsten oxide which was carried out at 375 °C. The as deposited tungsten oxide films were then annealed under flow (0.5 L min⁻¹) of air in the AACVD reactor at 500 °C to ensure complete oxidation and formation of WO₃.

Table S1: Operating parameters of the plasma jet.

Parameter	Value
Generator power	50 W
Electrode voltage amplitude	2 – 3 kV
Plasma power	0.5 - 2 W
Excitation frequency	13.56 MHz
Modulation frequency	20 kHz
Duty cycle	20 %
Temperature	350 - 380 K

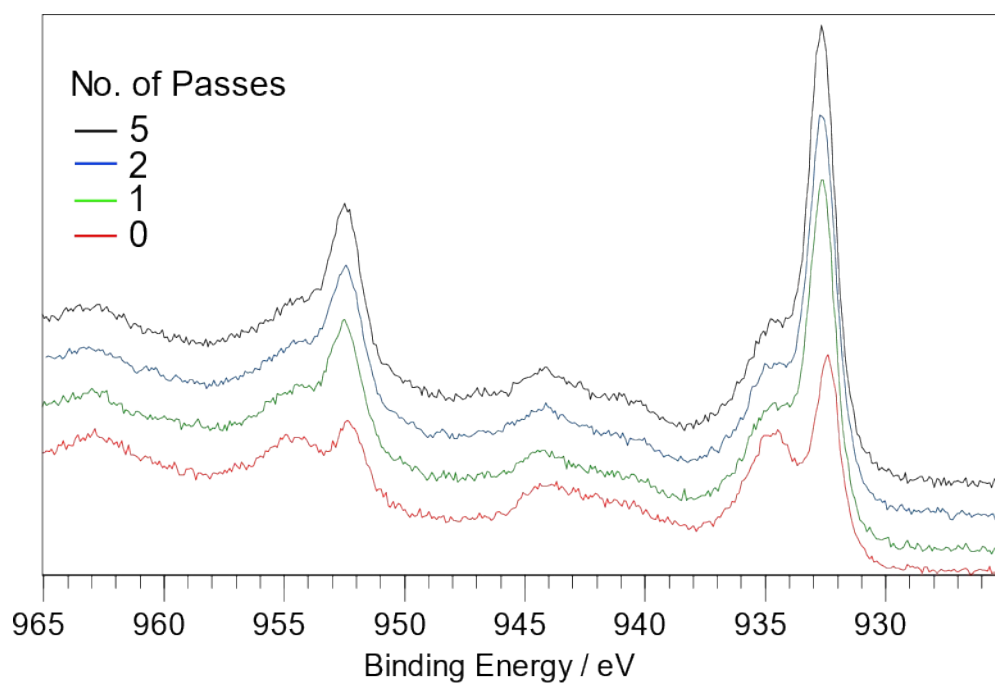


Figure S1: Cu 2p X-ray photoelectron spectra of the Cu₂O film before / after plasma treatment and increasing plasma jet passes over the surface.

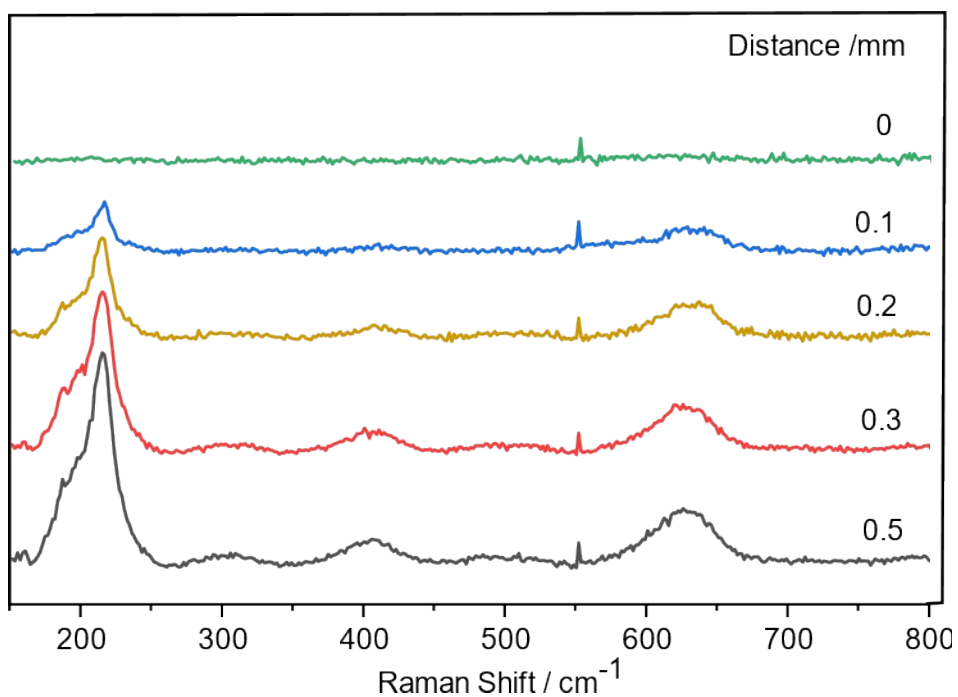


Figure S2: Raman spectra of the plasma treated copper track after 5 passes. Spectra taken along a 0.5 mm line extending out from the track centre(0 mm) into the Cu_2O pristine (0.5 mm) surface.

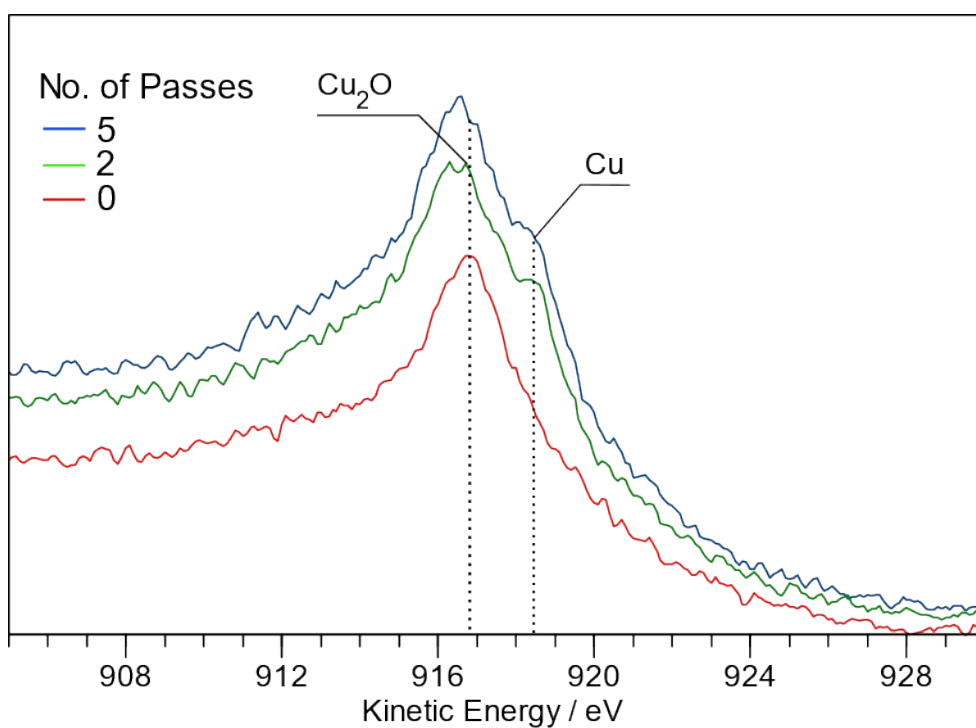


Figure S3: Auger electron spectra of the Cu_2O film before and after plasma treatment.

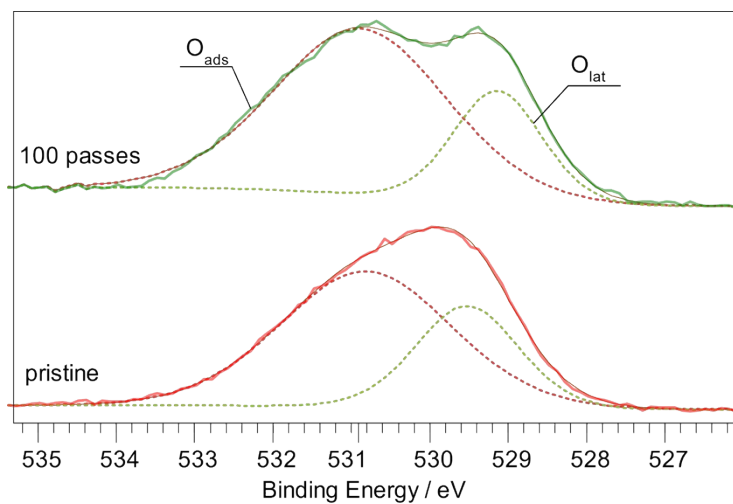


Figure S4: O 1s X-ray photoelectron spectrum of the pristine and reduced TiO_2 surface with deconvoluted lattice (O_{lat}) and adsorbed (O_{ads}) oxygen components.

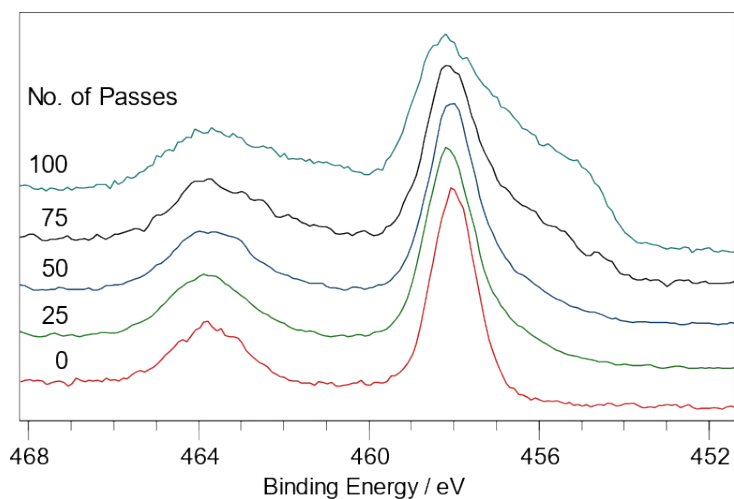


Figure S5: Ti 2p X-ray photoelectron spectra TiO_2 film before / after plasma treatment and increasing plasma jet passes over the surface.

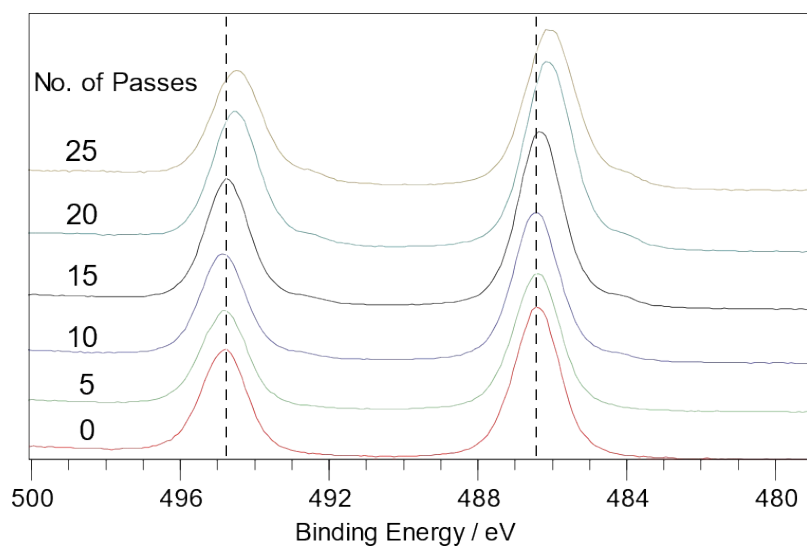


Figure S6: Sn 3d X-ray photoelectron spectra of the SnO₂ surface before / after plasma treatment and increasing plasma jet passes over the surface.

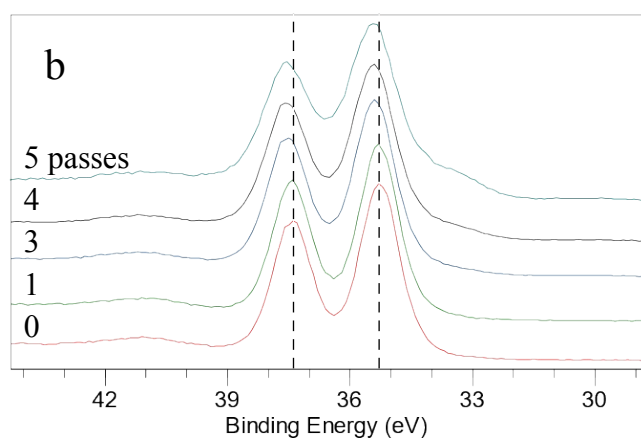
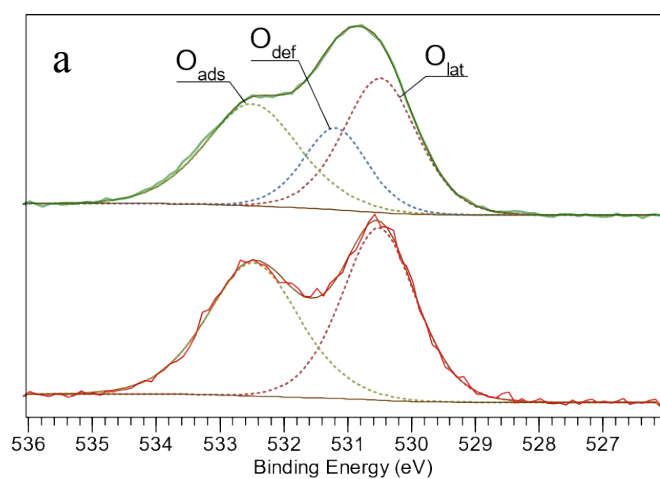


Figure S7: XPS spectra of O 1s from treated (green) and pristine (red) (a) and high-resolution W 4f XPS spectra from WO₃ surfaces as a function of number of passes.

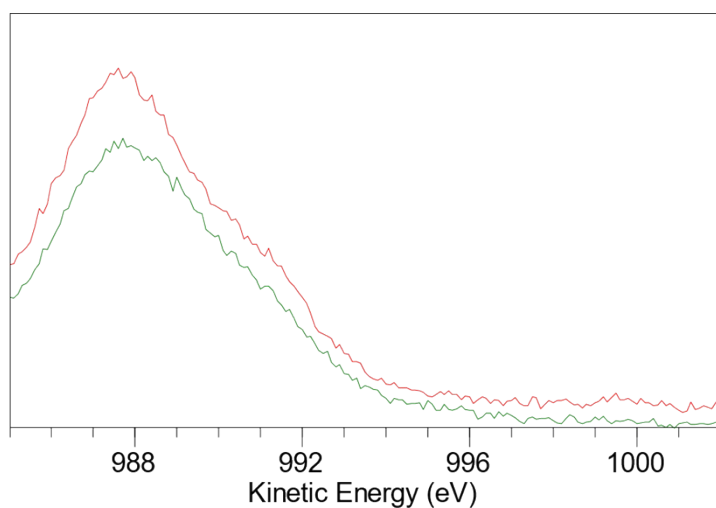


Figure S8: Zn LMM Auger electron spectra for treated (green) and pristine (red).

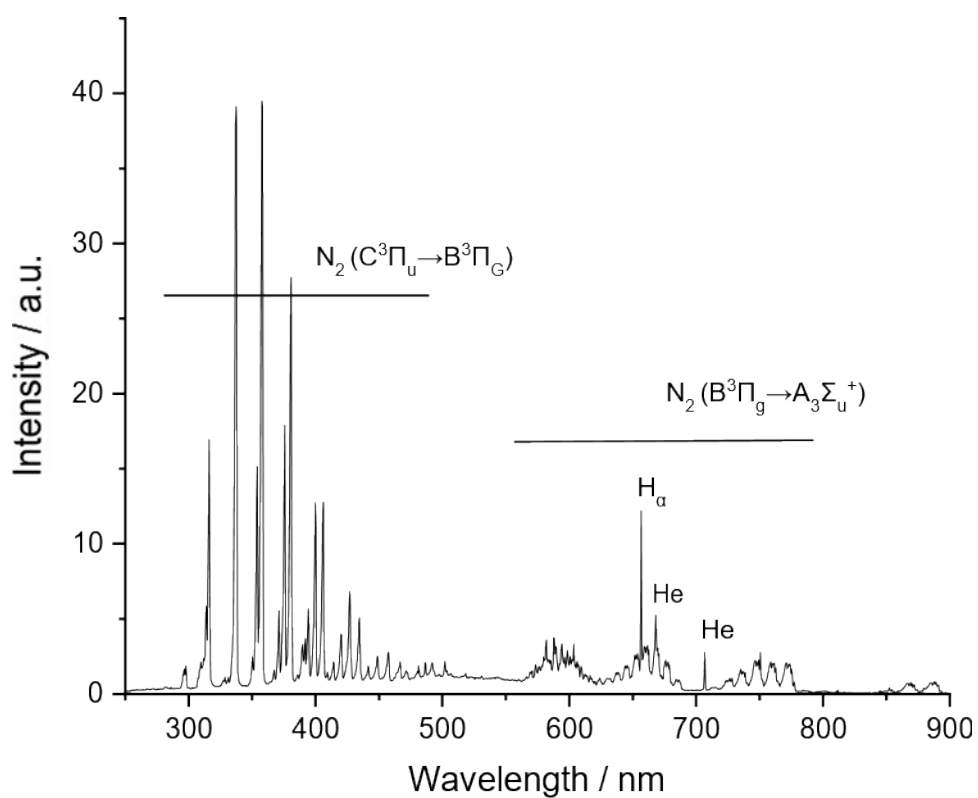


Figure S9: Optical emission spectrum of the plasma plume in the UV/Vis range.